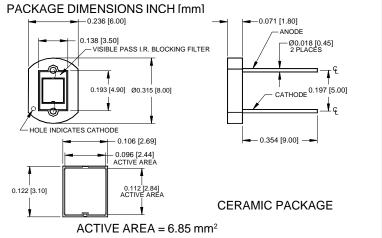
PHOTONIC DETECTORS INC.

Silicon Photodiode, Visible Light Detector Type PDV-V418





FEATURES

- Visible response
- Low dark current
- Good linearity
- Low noise

DESCRIPTION

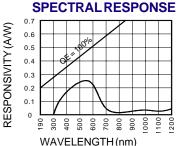
The **PDV-V418** is a silicon PIN photodiode, with a built in visible pass, I.R. blocking optical filter. Housed in a black ceramic package with two leads. Designed for photovoltaic operation with 0 volt bias.

APPLICATIONS

- Camera exposure meter
- Light meters
- Visible detector

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

				,	
SYMBOL	PARAMETER	MIN	MAX	UNITS	
Vbr	Reverse Voltage		10	V	
T _{stg}	Storage Temperature	-20	+80	°C	
To	Operating Temperature Range	-20	+60	°C	
Ts	Soldering Temperature*		+240	°C	
I _L	Light Current		0.5	mA	



*1/16 inch from case for 3 secs max

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
lsc	Short Circuit Current	H = 100 fc, 2850 K	5.75	7.45		μ A
ΙD	Dark Current	H = 0, V _R = 10 V		75	150	pА
Rsн	Shunt Resistance	H = 0, V _R = 10 mV	1.0	1.5		GΩ
TC Rsh	RsH Temp. Coefficient	H = 0, V _R = 10 mV		-8		%/°C
CJ	Junction Capacitance	$H = 0, V_R = 0 V^{**}$		800	1000	pF
λrange	Spectral Application Range	Spot Scan	320		730	nm
λρ	Spectral Response - Peak	Spot Scan		560		nm
Vbr	Breakdown Voltage	I = 10 μA	10	15		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		5x10 ⁻¹⁴		W/ √ Hz
tr	Response Time	$RL = 1 K\Omega V_R = 10 V$		500		nS

Information in this technical data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice. **f=1 MHz [FORM NO. 100-PDV-V418 REV A]